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# SPECIFICATION

Device Name : IGBT Module

Type Name : 2MBI150UB-120

Spec. No. : MS5F 5483

Fuji Electric Co.,Ltd.  
Matsumoto Factory

|         | DATE         | NAME        | APPROVED   | Fuji Electric Co.,Ltd. |           |        |  |
|---------|--------------|-------------|------------|------------------------|-----------|--------|--|
| DRAWN   | Jun.- 06-'03 | Y.Kobayashi | T.Fujihira | DWG.NO.                | MS5F 5483 | 1 / 13 |  |
| CHECKED | Jun.- 06-'03 | T.Miyasaka  |            |                        |           |        |  |
|         |              | K.Yamada    |            |                        |           |        |  |

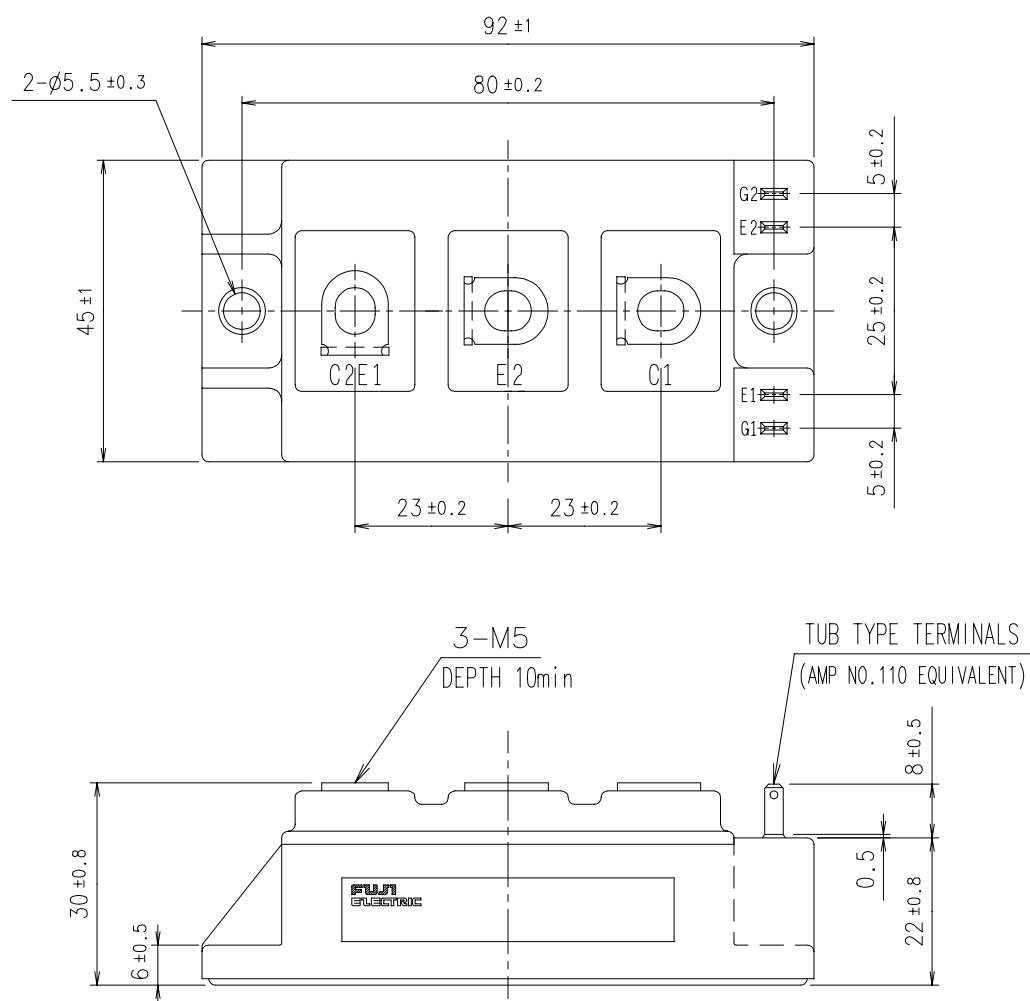
# Revised Records

[illegible]

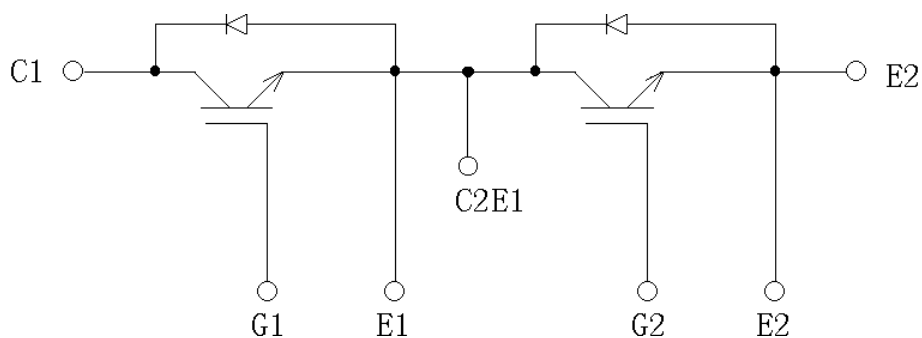
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# 2MBI150UB-120

## 1. Outline Drawing ( Unit : mm )



## 2. Equivalent circuit



**Fuji Electric Co.,Ltd.**

DWG.NO.

MS5F 5483

3 / 13

H04-004-03

### 3. Absolute Maximum Ratings ( at Tc= 25°C unless otherwise specified )

| Items                       |                                     | Symbols      | Conditions |  | Maximum Ratings | Units |
|-----------------------------|-------------------------------------|--------------|------------|--|-----------------|-------|
| Collector-Emitter voltage   |                                     | VCES         |            |  | 1200            | V     |
| Gate-Emitter voltage        |                                     | VGES         |            |  | ±20             | V     |
| Collector current           | Ic                                  | Continuous   | Tc=25°C    |  | 200             | A     |
|                             |                                     |              | Tc=80°C    |  | 150             |       |
|                             | Icp                                 | 1ms          | Tc=25°C    |  | 400             |       |
|                             |                                     |              | Tc=80°C    |  | 300             |       |
|                             | -Ic                                 |              |            |  | 150             |       |
|                             |                                     | -Ic pulse    |            |  | 300             |       |
| Collector Power Dissipation |                                     | Pc           | 1 device   |  | 780             | W     |
| Junction temperature        |                                     | Tj           |            |  | 150             | °C    |
| Storage temperature         |                                     | Tstg         |            |  | -40 ~ +125      |       |
| Isolation voltage           | between terminal and copper base *1 | Viso         | AC : 1min. |  | 2500            | VAC   |
| Screw Torque                |                                     | Mounting *2  |            |  | 3.5             | N·m   |
|                             |                                     | Terminals *2 |            |  | 3.5             |       |

(\*1) All terminals should be connected together when isolation test will be done.

(\*2) Recommendable Value : Mounting 2.5~3.5 Nm (M5)

### 4. Electrical characteristics ( at Tj= 25°C unless otherwise specified)

| Items                                   | Symbols                | Conditions                                        |          | Characteristics |      |      | Units |
|-----------------------------------------|------------------------|---------------------------------------------------|----------|-----------------|------|------|-------|
|                                         |                        |                                                   |          | min.            | typ. | max. |       |
| Zero gate voltage<br>Collector current  | ICES                   | VGE = 0V<br>VCE = 1200V                           |          | -               | -    | 2.0  | mA    |
| Gate-Emitter<br>leakage current         | IGES                   | VCE = 0V<br>VGE=±20V                              |          | -               | -    | 400  | nA    |
| Gate-Emitter<br>threshold voltage       | VGE(th)                | VCE = 20V<br>Ic = 150mA                           |          | 4.5             | 6.5  | 8.5  | V     |
| Collector-Emitter<br>saturation voltage | VCE(sat)<br>(terminal) | VGE=15V                                           | Tj= 25°C | -               | 1.90 | 2.25 | V     |
|                                         |                        |                                                   | Tj=125°C | -               | 2.15 | -    |       |
|                                         | VCE(sat)<br>(chip)     | Ic = 150A                                         | Tj= 25°C | -               | 1.75 | 2.10 |       |
|                                         |                        |                                                   | Tj=125°C | -               | 2.00 | -    |       |
| Input capacitance                       | Cies                   | VCE=10V,VGE=0V,f=1MHz                             |          | -               | 17   | -    | nF    |
| Turn-on time                            | ton                    | Vcc = 600V<br>Ic = 150A<br>VGE=±15V<br>Rg = 4.7 Ω |          | -               | 0.36 | 1.20 | μs    |
|                                         | tr                     |                                                   |          | -               | 0.21 | 0.60 |       |
|                                         | tr (i)                 |                                                   |          | -               | 0.03 | -    |       |
| Turn-off time                           | toff                   |                                                   |          | -               | 0.37 | 1.00 |       |
|                                         | tf                     |                                                   |          | -               | 0.07 | 0.30 |       |
| Forward on voltage                      | VF<br>(terminal)       | VGE=0V                                            | Tj= 25°C | -               | 1.75 | 2.05 | V     |
|                                         |                        |                                                   | Tj=125°C | -               | 1.85 | -    |       |
|                                         | VF<br>(chip)           | IF = 150A                                         | Tj= 25°C | -               | 1.60 | 1.90 |       |
|                                         |                        |                                                   | Tj=125°C | -               | 1.70 | -    |       |
| Reverse recovery time                   | trr                    | IF = 150A                                         |          | -               | -    | 0.35 | μs    |
| Lead resistance, terminal-chip *        | R lead                 |                                                   |          | -               | 0.97 | -    | m Ω   |

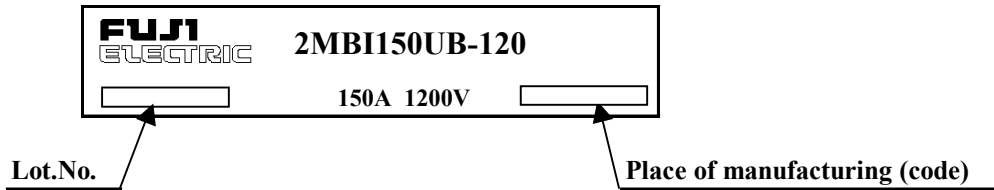
(\*) Biggest internal terminal resistance among arm.

## 5. Thermal resistance characteristics

| Items                        | Symbols  | Conditions                | Characteristics |       |      | Units |
|------------------------------|----------|---------------------------|-----------------|-------|------|-------|
|                              |          |                           | min.            | typ.  | max. |       |
| Thermal resistance(1 device) | Rth(j-c) | IGBT                      | -               | -     | 0.16 | °C/W  |
|                              |          | FWD                       | -               | -     | 0.24 |       |
| Contact Thermal resistance   | Rth(c-f) | with Thermal Compound (※) | -               | 0.025 | -    |       |

※ This is the value which is defined mounting on the additional cooling fin with thermal compound.

## 6. Indication on module



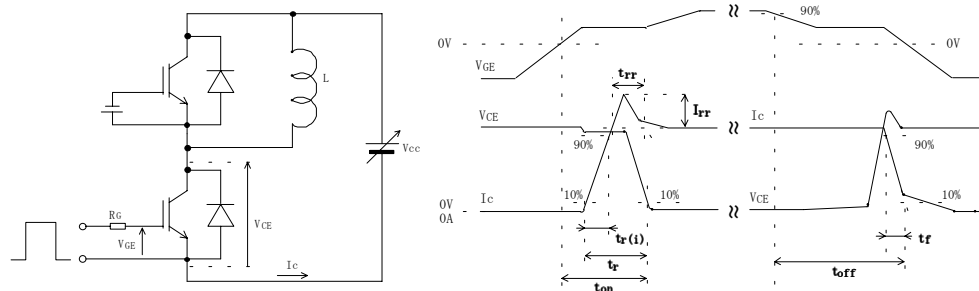
## 7. Applicable category

This specification is applied to IGBT Module named 2MBI150UB-120 .

## 8. Storage and transportation notes

- The module should be stored at a standard temperature of 5 to 35°C and humidity of 45 to 75% .
- Store modules in a place with few temperature changes in order to avoid condensation on the module surface.
- Avoid exposure to corrosive gases and dust.
- Avoid excessive external force on the module.
- Store modules with unprocessed terminals.
- Do not drop or otherwise shock the modules when transporting.

## 9. Definitions of switching time



## 10. Packing and Labeling

Display on the packing box

- Logo of production
- Type name
- Lot No
- Products quantity in a packing box

# 11. Reliability test results

## Reliability Test Items

| Test categories   | Test items                      | Test methods and conditions                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                             | Reference norms<br>EIAJ ED-4701<br>(Aug.-2001 edition) | Number of sample | Acceptance number |
|-------------------|---------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------------------------------------------|------------------|-------------------|
| Mechanical Tests  | 1 Terminal Strength (Pull test) | Pull force : 40N<br>Test time : 10±1 sec.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                               | Test Method 401<br>Method I                            | 5                | ( 0 : 1 )         |
|                   | 2 Mounting Strength             | Screw torque : 2.5 ~ 3.5 N·m (M5)<br>Test time : 10±1 sec.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                              | Test Method 402<br>method II                           | 5                | ( 0 : 1 )         |
|                   | 3 Vibration                     | Range of frequency : 10 ~ 500Hz<br>Sweeping time : 15 min.<br>Acceleration : 100m/s <sup>2</sup><br>Sweeping direction : Each X,Y,Z axis<br>Test time : 6 hr. (2hr./direction)                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                          | Test Method 403<br>Reference 1<br>Condition code B     | 5                | ( 0 : 1 )         |
|                   | 4 Shock                         | Maximum acceleration : 5000m/s <sup>2</sup><br>Pulse width : 1.0msec.<br>Direction : Each X,Y,Z axis<br>Test time : 3 times/direction                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                   | Test Method 404<br>Condition code B                    | 5                | ( 0 : 1 )         |
| Environment Tests | 1 High Temperature Storage      | Storage temp. : 125±5 °C<br>Test duration : 1000hr.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                     | Test Method 201                                        | 5                | ( 0 : 1 )         |
|                   | 2 Low Temperature Storage       | Storage temp. : -40±5 °C<br>Test duration : 1000hr.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                     | Test Method 202                                        | 5                | ( 0 : 1 )         |
|                   | 3 Temperature Humidity Storage  | Storage temp. : 85±2 °C<br>Relative humidity : 85±5%<br>Test duration : 1000hr.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                         | Test Method 103<br>Test code C                         | 5                | ( 0 : 1 )         |
|                   | 4 Unsaturated Pressure Cooker   | Test temp. : 120±2 °C<br>Atmospheric pressure : 1.7 × 10 <sup>5</sup> Pa<br>Test humidity : 85±5%<br>Test duration : 96hr.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                              | Test Method 103<br>Test code E                         | 5                | ( 0 : 1 )         |
|                   | 5 Temperature Cycle             | Test temp. :<br><div style="display: inline-block; vertical-align: middle;"> <div style="display: inline-block; vertical-align: middle;"> <div style="display: inline-block; vertical-align: middle;">Low temp. -40±5 °C</div> <div style="display: inline-block; vertical-align: middle;">High temp. 125 ±5 °C</div> <div style="display: inline-block; vertical-align: middle;">RT 5 ~ 35 °C</div> </div> <div style="display: inline-block; vertical-align: middle;"> <div style="display: inline-block; vertical-align: middle;">Dwell time : High ~ RT ~ Low ~ RT<br/>1hr. 0.5hr. 1hr. 0.5hr.</div> <div style="display: inline-block; vertical-align: middle;">Number of cycles : 100 cycles</div> </div> </div>                                                  | Test Method 105                                        | 5                | ( 0 : 1 )         |
|                   | 6 Thermal Shock                 | Test temp. :<br><div style="display: inline-block; vertical-align: middle;"> <div style="display: inline-block; vertical-align: middle;">High temp. 100<sup>+0</sup> °C</div> <div style="display: inline-block; vertical-align: middle;">Low temp. 0<sup>+5</sup> °C</div> </div> <div style="display: inline-block; vertical-align: middle;"> <div style="display: inline-block; vertical-align: middle;">Used liquid : Water with ice and boiling water</div> <div style="display: inline-block; vertical-align: middle;">Dipping time : 5 min. par each temp.</div> <div style="display: inline-block; vertical-align: middle;">Transfer time : 10 sec.</div> <div style="display: inline-block; vertical-align: middle;">Number of cycles : 10 cycles</div> </div> | Test Method 307<br>method I<br>Condition code A        | 5                | ( 0 : 1 )         |

## Reliability Test Items

| Test categories | Test items                                               | Test methods and conditions                                                                                                                                                                                                                     | Reference norms<br>EIAJ ED-4701<br>(Aug.-2001 edition) | Number of sample | Acceptance number |
|-----------------|----------------------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------------------------------------------|------------------|-------------------|
| Endurance Tests | 1 High temperature Reverse Bias                          | Test temp. : $T_a = 125 \pm 5 \text{ }^{\circ}\text{C}$<br>( $T_j \leq 150 \text{ }^{\circ}\text{C}$ )<br>Bias Voltage : $V_C = 0.8 \times V_{CES}$<br>Bias Method : Applied DC voltage to C-E<br>$V_{GE} = 0V$<br>Test duration : 1000hr.      | Test Method 101                                        | 5                | ( 0 : 1 )         |
|                 | 2 High temperature Bias (for gate)                       | Test temp. : $T_a = 125 \pm 5 \text{ }^{\circ}\text{C}$<br>( $T_j \leq 150 \text{ }^{\circ}\text{C}$ )<br>Bias Voltage : $V_C = V_{GE} = +20V$ or $-20V$<br>Bias Method : Applied DC voltage to G-E<br>$V_{CE} = 0V$<br>Test duration : 1000hr. | Test Method 101                                        | 5                | ( 0 : 1 )         |
|                 | 3 Temperature Humidity Bias                              | Test temp. : $85 \pm 2 \text{ }^{\circ}\text{C}$<br>Relative humidity : $85 \pm 5\%$<br>Bias Voltage : $V_C = 0.8 \times V_{CES}$<br>Bias Method : Applied DC voltage to C-E<br>$V_{GE} = 0V$<br>Test duration : 1000hr.                        | Test Method 102<br>Condition code C                    | 5                | ( 0 : 1 )         |
|                 | 4 Intermittent Operating Life (Power cycle) ( for IGBT ) | ON time : 2 sec.<br>OFF time : 18 sec.<br>Test temp. : $\Delta T_j = 100 \pm 5 \text{ deg}$<br>$T_j \leq 150 \text{ }^{\circ}\text{C}$ , $T_a = 25 \pm 5 \text{ }^{\circ}\text{C}$<br>Number of cycles : 15000 cycles                           | Test Method 106                                        | 5                | ( 0 : 1 )         |

## Failure Criteria

| Item                      | Characteristic                                            | Symbol                    | Failure criteria  |             | Unit | Note |
|---------------------------|-----------------------------------------------------------|---------------------------|-------------------|-------------|------|------|
|                           |                                                           |                           | Lower limit       | Upper limit |      |      |
| Electrical characteristic | Leakage current                                           | ICES                      | -                 | USL×2       | mA   |      |
|                           |                                                           | ±IGES                     | -                 | USL×2       | μA   |      |
|                           | Gate threshold voltage                                    | VGE(th)                   | LSL×0.8           | USL×1.2     | mA   |      |
|                           | Saturation voltage                                        | VCE(sat)                  | -                 | USL×1.2     | V    |      |
|                           | Forward voltage                                           | VF                        | -                 | USL×1.2     | V    |      |
|                           | Thermal resistance                                        | IGBT<br>Δ VGE<br>or Δ VCE | -                 | USL×1.2     | mV   |      |
|                           |                                                           | FWD<br>Δ VF               | -                 | USL×1.2     | mV   |      |
| Visual inspection         | Isolation voltage                                         | Viso                      | Broken insulation |             | -    |      |
|                           | Visual inspection<br>Peeling<br>Plating<br>and the others | -                         | The visual sample |             | -    |      |

LSL : Lower specified limit.

USL : Upper specified limit.

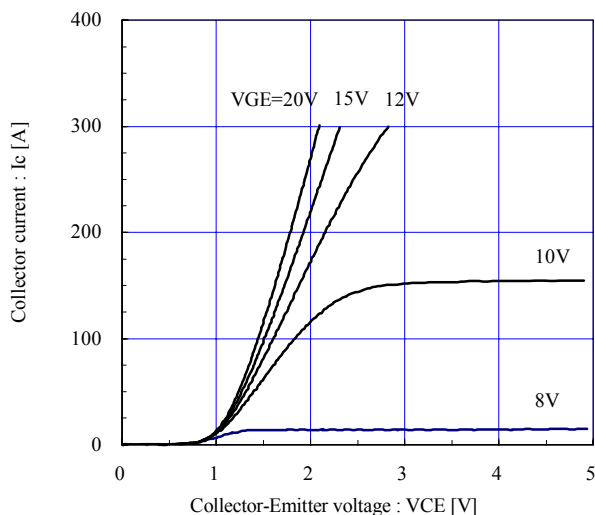
Note : Each parameter measurement read-outs shall be made after stabilizing the components at room ambient for 2 hours minimum, 24 hours maximum after removal from the tests. And in case of the wetting tests, for example, moisture resistance tests, each component shall be made wipe or dry completely before the measurement.

## Reliability Test Results

| Test categories   | Test items                                                | Reference norms<br>EIAJ ED-4701<br>(Aug.-2001 edition) | Number of test sample | Number of failure sample |
|-------------------|-----------------------------------------------------------|--------------------------------------------------------|-----------------------|--------------------------|
| Mechanical Tests  | 1 Terminal Strength (Pull test)                           | Test Method 401<br>Method I                            | 5                     | 0                        |
|                   | 2 Mounting Strength                                       | Test Method 402<br>method II                           | 5                     | 0                        |
|                   | 3 Vibration                                               | Test Method 403<br>Condition code B                    | 5                     | 0                        |
|                   | 4 Shock                                                   | Test Method 404<br>Condition code B                    | 5                     | 0                        |
| Environment Tests | 1 High Temperature Storage                                | Test Method 201                                        | 5                     | 0                        |
|                   | 2 Low Temperature Storage                                 | Test Method 202                                        | 5                     | 0                        |
|                   | 3 Temperature Humidity Storage                            | Test Method 103<br>Test code C                         | 5                     | 0                        |
|                   | 4 Unsaturated Pressure Cooker                             | Test Method 103<br>Test code E                         | 5                     | 0                        |
|                   | 5 Temperature Cycle                                       | Test Method 105                                        | 5                     | 0                        |
|                   | 6 Thermal Shock                                           | Test Method 307<br>method I<br>Condition code A        | 5                     | 0                        |
| Endurance Tests   | 1 High temperature Reverse Bias                           | Test Method 101                                        | 5                     | 0                        |
|                   | 2 High temperature Bias ( for gate )                      | Test Method 101                                        | 5                     | 0                        |
|                   | 3 Temperature Humidity Bias                               | Test Method 102<br>Condition code C                    | 5                     | 0                        |
|                   | 4 Intermitted Operating Life (Power cycling) ( for IGBT ) | Test Method 106                                        | 5                     | 0                        |

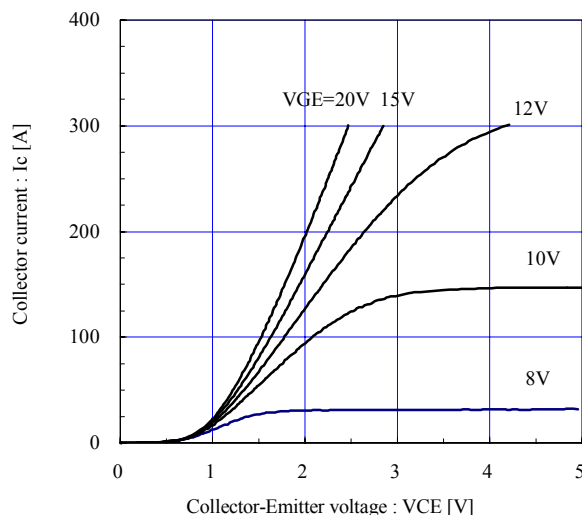
Collector current vs. Collector-Emitter voltage (typ.)

$T_j = 25^\circ\text{C}$  / chip



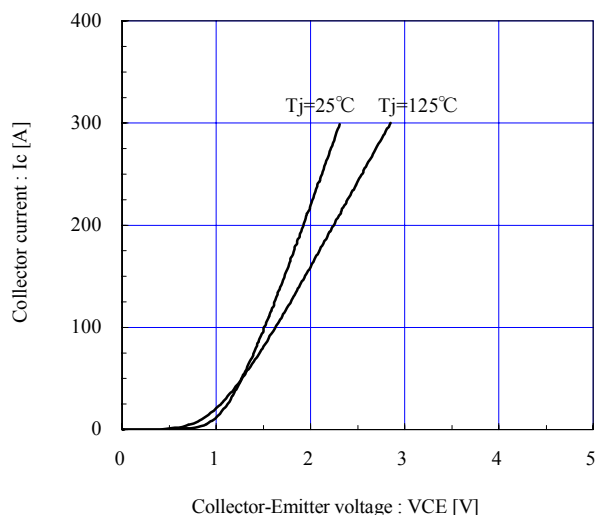
Collector current vs. Collector-Emitter voltage (typ.)

$T_j = 125^\circ\text{C}$  / chip



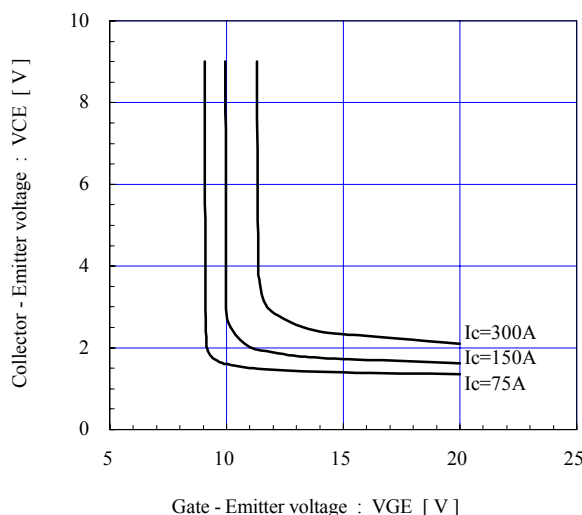
Collector current vs. Collector-Emitter voltage (typ.)

$V_{GE} = 15\text{V}$  / chip

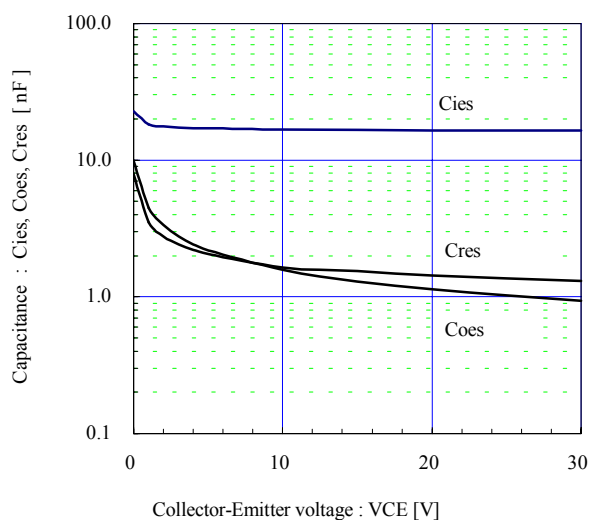


Collector-Emitter voltage vs. Gate-Emitter voltage (typ.)

$T_j = 25^\circ\text{C}$  / chip

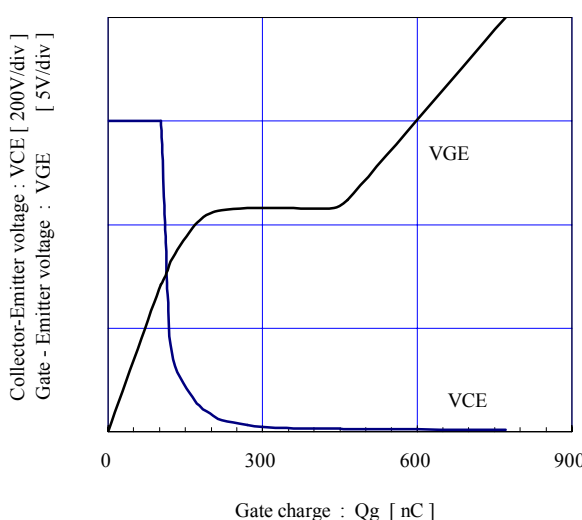


Capacitance vs. Collector-Emitter voltage (typ.)



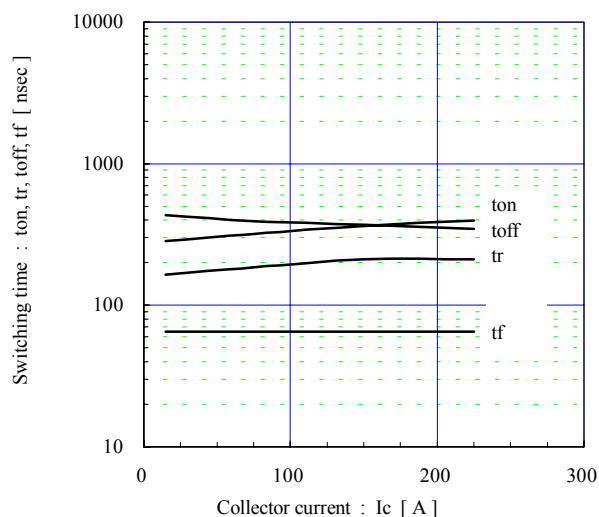
Dynamic Gate charge (typ.)

$V_{CC} = 600\text{V}$ ,  $I_C = 150\text{A}$ ,  $T_j = 25^\circ\text{C}$

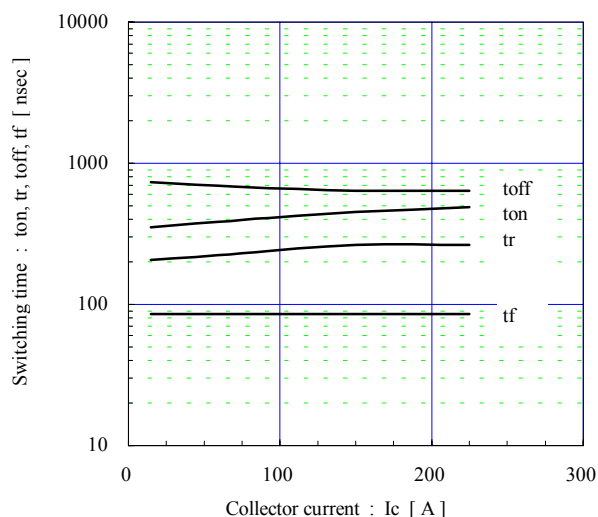


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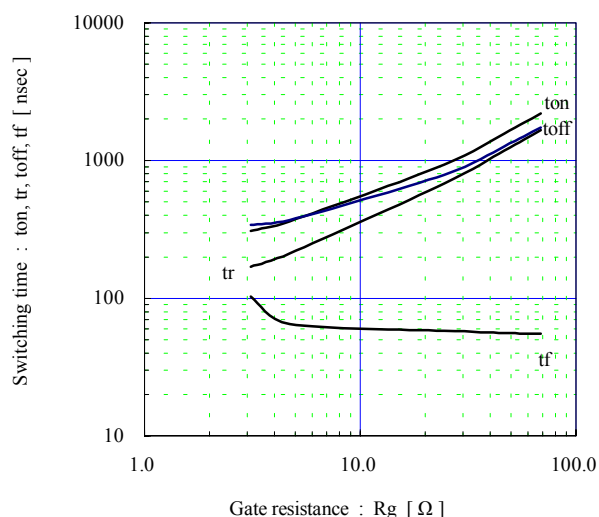
Switching time vs. Collector current (typ.)  
 $V_{cc}=600V$ ,  $V_{GE}=\pm 15V$ ,  $R_g=4.7\Omega$ ,  $T_j=25^\circ C$



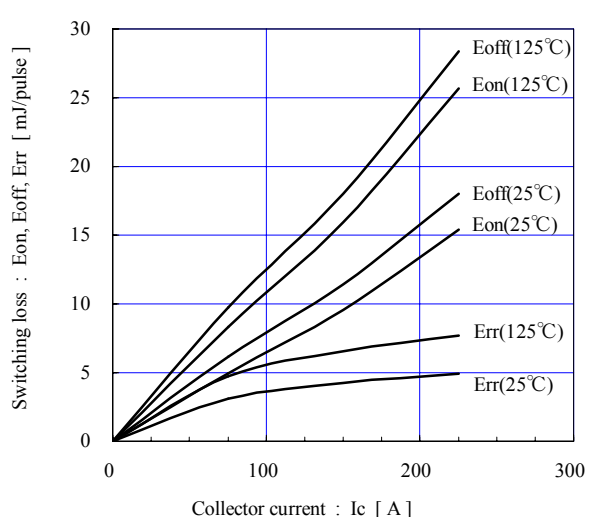
Switching time vs. Collector current (typ.)  
 $V_{cc}=600V$ ,  $V_{GE}=\pm 15V$ ,  $R_g=4.7\Omega$ ,  $T_j=125^\circ C$



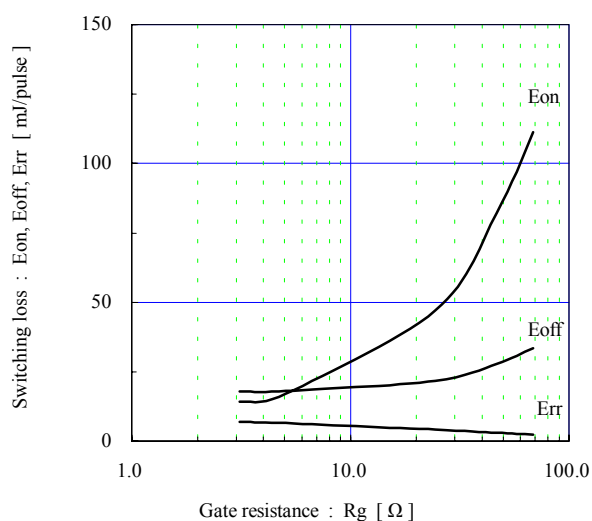
Switching time vs. Gate resistance (typ.)  
 $V_{cc}=600V$ ,  $I_c=150A$ ,  $V_{GE}=\pm 15V$ ,  $T_j=25^\circ C$



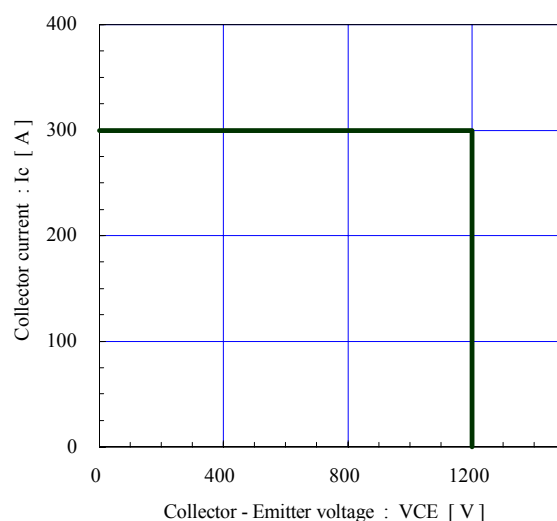
Switching loss vs. Collector current (typ.)  
 $V_{cc}=600V$ ,  $V_{GE}=\pm 15V$ ,  $R_g=4.7\Omega$



Switching loss vs. Gate resistance (typ.)  
 $V_{cc}=600V$ ,  $I_c=150A$ ,  $V_{GE}=\pm 15V$ ,  $T_j=125^\circ C$

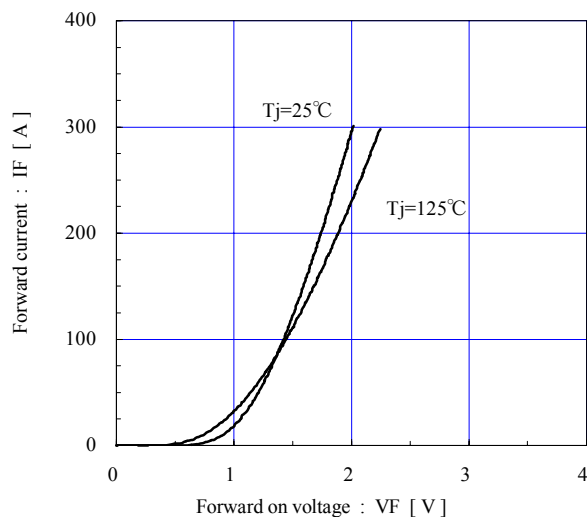


Reverse bias safe operating area (max.)  
 $+V_{GE}=15V$ ,  $-V_{GE}\leq 15V$ ,  $R_g\geq 4.7\Omega$ ,  $T_j\leq 125^\circ C$

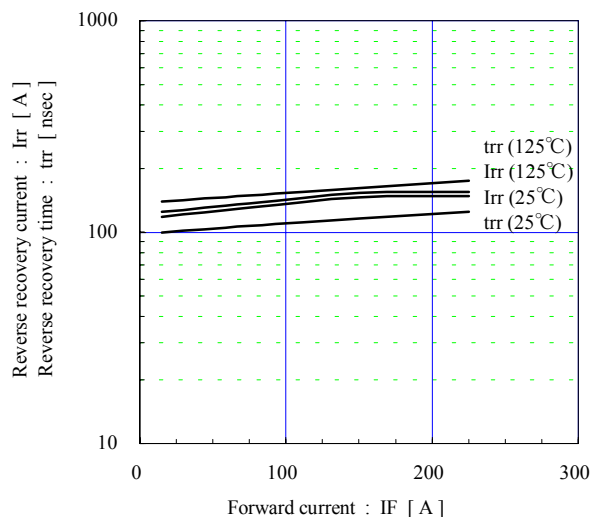


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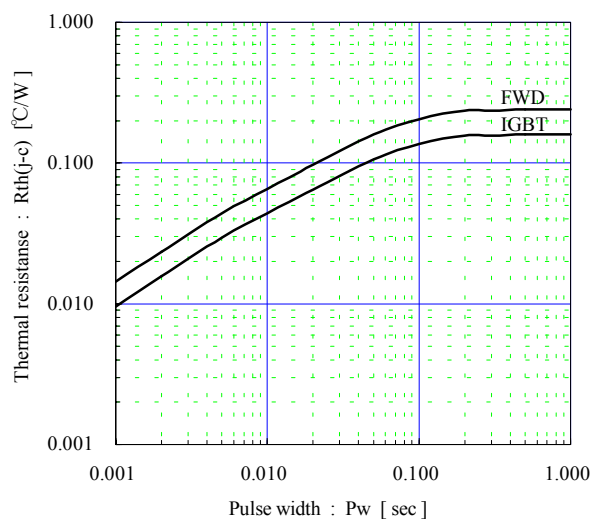
Forward current vs. Forward on voltage (typ.)  
chip



Reverse recovery characteristics (typ.)  
 $V_{CC}=600V$ ,  $V_{GE}=\pm 15V$ ,  $R_g=4.7\Omega$



Transient thermal resistance (max.)



## Warnings

- This product shall be used within its absolute maximum rating (voltage, current, and temperature).  
This product may be broken in case of using beyond the ratings.  
製品の絶対最大定格(電圧, 電流, 温度等)の範囲内で御使用下さい。  
絶対最大定格を超えて使用すると、素子が破壊する場合があります。
- Connect adequate fuse or protector of circuit between three-phase line and this product to prevent the equipment from causing secondary destruction.  
万一の不慮の事故で素子が破壊した場合を考慮し、商用電源と本製品の間に適切な容量のヒューズ又はブレーカーを必ず付けて2次破壊を防いでください。
- Use this product after realizing enough working on environment and considering of product's reliability life.  
This product may be broken before target life of the system in case of using beyond the product's reliability life.  
製品の使用環境を十分に把握し、製品の信頼性寿命が満足できるか検討の上、本製品を適用して下さい。  
製品の信頼性寿命を超えて使用した場合、装置の目標寿命より前に素子が破壊する場合があります。
- If the product had been used in the environment with acid, organic matter, and corrosive gas (hydrogen sulfide, sulfurous acid gas), the product's performance and appearance can not be ensured easily.  
酸・有機物・腐食性ガス(硫化水素, 亜硫酸ガス等)を含む環境下で使用された場合、製品機能・外觀などの保証は致しかねます。
- Use this product within the power cycle curve (Technical Rep.No. : MT5F12959)  
本製品は、パワーサイクル寿命カーブ以下で使用下さい(技術資料No.: MT5F12959)
- Never add mechanical stress to deform the main or control terminal.  
The deformed terminal may cause poor contact problem.  
主端子及び制御端子に応力を与えて変形させないで下さい。 端子の変形により、接触不良などを引き起こす場合があります。
- According to the outline drawing, select proper length of screw for main terminal.  
Longer screws may break the case.  
本製品に使用する主端子用のネジの長さは、外形図に従い正しく選定下さい。  
ネジが長いとケースが破損する場合があります。
- Use this product with keeping the cooling fin's flatness between screw holes within 100um at 100mm and the roughness within 10um. Also keep the tightening torque within the limits of this specification.  
Improper handling may cause isolation breakdown and this may lead to a critical accident.  
冷却フィンにネジ取り付け位置間で平坦度を100mmで100um以下、表面の粗さは10um以下にして下さい。 誤った取り扱いをすると絶縁破壊を起こし、重大事故に発展する場合があります。
- It shall be confirmed that IGBT's operating locus of the turn-off voltage and current are within the RBSOA specification. This product may be broken if the locus is out of the RBSOA.  
ターンオフ電圧・電流の動作軌跡がRBSOA仕様内にあることを確認して下さい。  
RBSOAの範囲を超えて使用すると素子が破壊する可能性があります。
- If excessive static electricity is applied to the control terminals, the devices may be broken.  
Implement some countermeasures against static electricity.  
制御端子に過大な静電気が印加された場合、素子が破壊する場合があります。  
取り扱い時は静電気対策を実施して下さい。
- Never add the excessive mechanical stress to the main or control terminals when the product is applied to equipments. The module structure may be broken.  
素子を装置に実装する際に、主端子や制御端子に過大な応力を与えないで下さい。  
端子構造が破壊する可能性があります。
- In case of insufficient -VGE, erroneous turn-on of IGBT may occur.  
-VGE shall be set enough value to prevent this malfunction. (Recommended value : -VGE = -15V)  
逆バイアスゲート電圧-VGEが不足しますと誤点弧を起こす可能性があります。  
誤点弧を起こさない為に-VGEは十分な値で設定して下さい。(推奨値 : -VGE = -15V)
- In case of higher turn-on dv/dt of IGBT, erroneous turn-on of opposite arm IGBT may occur.  
Use this product in the most suitable drive conditions, such as +VGE, -VGE, RG to prevent the malfunction.  
ターンオン dv/dt が高いと対抗アームのIGBTが誤点弧を起こす可能性があります。  
誤点弧を起こさない為の最適なドライブ条件(+VGE, -VGE, RG等)でご使用下さい。
- This product may be broken by avalanche in case of VCE beyond maximum rating VCES is applied between C-E terminals. Use this product within its absolute maximum voltage.  
VCESを超えた電圧が印加された場合、アバランシェを起こして素子破壊する場合があります。  
VCEは必ず絶対定格の範囲内でご使用下さい。

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